

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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ULTRA LOW PHASE NOISE AMPLIFIER, 6 - 12 GHz

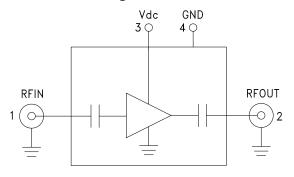


Typical Applications

The HMC-C072 is ideal for:

- Microwave Radio
- Military & Space
- Test Instrumentation
- VSAT

Functional Diagram



Features

Ultra Low Phase Noise: -167 dBc/Hz @ 1 kHz

Noise Figure: 4.5 dB

Gain: 11 dB Psat: 22 dBm

50 Ohm Matched Input/Output

Single Supply Voltage: +7V @ 170mA

Hermetically Sealed Module

Field Replaceable SMA Connectors
-55 °C to +85 °C Operating Temperature

General Description

The HMC-C072 is a GaAs HBT Ultra Low Noise Amplifier in a miniature, hermetic module designed to operate between 6 and 12 GHz. This high dynamic range amplifier module provides 11 dB of gain, 4.5 dB noise figure and up to 23 dB of output power with a single supply of +7V. The ultra low phase noise contribution of -167 dBc/Hz at 1 kHz offset, enables superior modulation accuracy within transceiver architectures. The wideband distributed amplifier I/O's are internally matched to 50 Ohms and DC blocked for robust performance. The module features removable SMA connectors which can be detached to allow direct connection of the I/O pins to a microstrip or coplanar circuit.

Electrical Specifications, $T_A = +25$ °C, Vdc = +7V

Parameter	Min.	Тур.	Max.	Units
	IVIIII.		IVIAX.	
Frequency Range		6 - 12		GHz
Gain	9	11		dB
Gain Flatness		±1		dB
Gain Variation Over Temperature		0.015		dB/ °C
Noise Figure		4.5		dB
Input Return Loss		15		dB
Output Return Loss		15		dB
Output Power for 1 dB Compression (P1dB)	17	20		dBm
Saturated Output Power (Psat)		22		dBm
Output Third Order Intercept (IP3)		34		dBm
Phase Noise @ 100 Hz, Psat, 10 GHz		-157		dBc/Hz
Phase Noise @ 1 kHz, Psat, 10 GHz		-167		dBc/Hz
Phase Noise @ 10 kHz, Psat, 10 GHz		-176		dBc/Hz
Phase Noise @ 100 kHz, Psat, 10 GHz		-180		dBc/Hz
Supply Current		170	200	mA

HMC-C072* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

DOCUMENTATION

Data Sheet

• HMC-C072 Data Sheet

DESIGN RESOURCES 🖵

- HMC-C072 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- · Symbols and Footprints

DISCUSSIONS

View all HMC-C072 EngineerZone Discussions.

SAMPLE AND BUY 🖵

Visit the product page to see pricing options.

TECHNICAL SUPPORT 🖳

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK 🖳

Submit feedback for this data sheet.

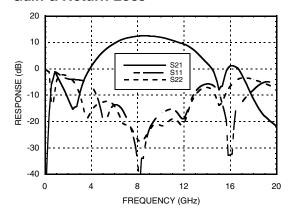
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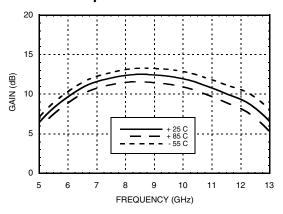


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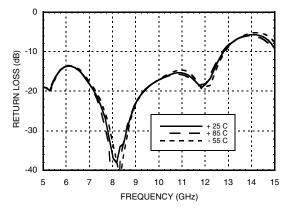
Gain & Return Loss



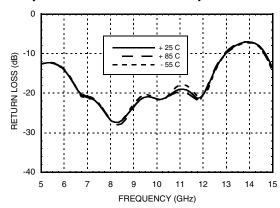
Gain vs. Temperature



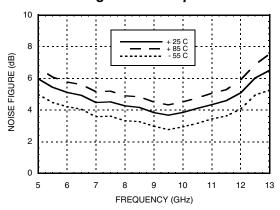
Input Return Loss vs. Temperature



Output Return Loss vs. Temperature



Noise Figure vs. Temperature

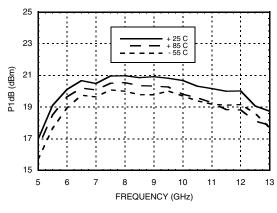




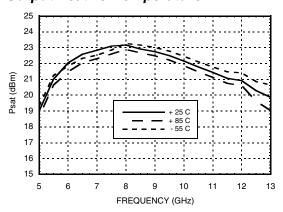


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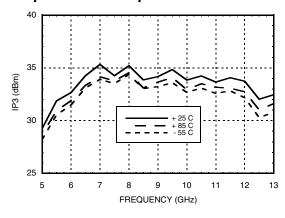
Output P1dB vs. Temperature



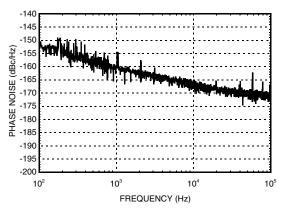
Output Psat vs. Temperature



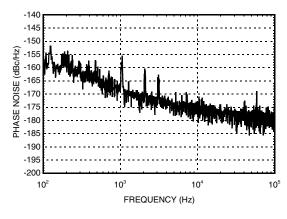
Output IP3 vs. Temperature



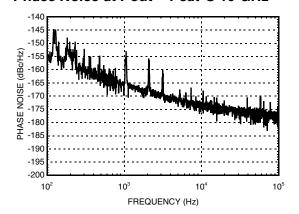
Phase Noise at Pout = 10 dBm @ 10 GHz



Phase Noise at Pout = P1dB @ 10 GHz



Phase Noise at Pout = Psat @ 10 GHz



AMPLIFIERS



v04.0711



ULTRA LOW PHASE NOISE AMPLIFIER, 6 - 12 GHz

Absolute Maximum Ratings

Bias Supply Voltage (Vdc)	+8V	
RF Input Power (RFIN)	+15 dBm	
Continuous Pdiss (T = 85 °C)	1.62W	
Channel Temperature	135 °C	
Thermal Resistance	20 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-55 to +85 °C	



Pin Descriptions

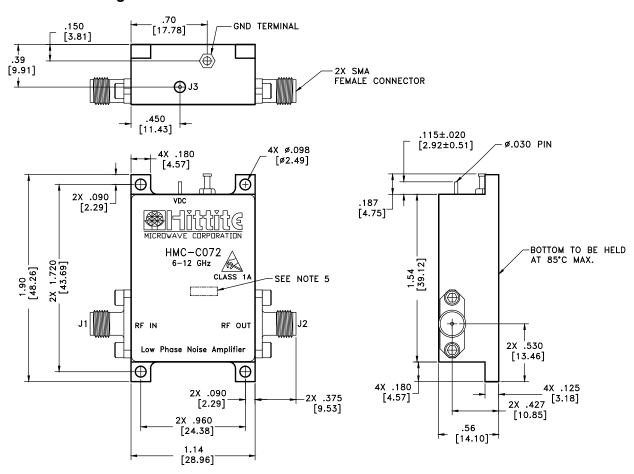
Pin Number	Function	Description	Interface Schematic	
1	RFIN & RF Ground	RF input connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	RFINO————————————————————————————————————	
2	RFOUT & RF Ground	RF output connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	→ ├─○ RFOUT	
3	Vdc	Power supply voltage for the amplifier. (+7V to +8V)	Vdc O	
4	GND	Power supply ground.	GND =	





ULTRA LOW PHASE NOISE AMPLIFIER, 6 - 12 GHz

Outline Drawing



Package Information

Package Type	C-16
Package Weight	107 gms ^[1]

[1] ±1 gms Tolerance

NOTES

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
- 2. FINISH: GOLD PLATE OVER NICKEL PLATE.
- 3. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. TOLERANCES:
 - 4.1 .XX = ±.02
- 4.2 .XXX = ±.010
- 5. MARK LOT NUMBER ON 0.080 X 0.250 LABEL WHERE SHOWN, WITH 0.030" MIN TEXT HEIGHT.



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AMPLIFIERS



ANALOGDEVICES

Notes:

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